TOSHIBA Transistor Silicon NPN Triple Diffused Type

2SC6010

High Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications

• High speed switching: $t_f = 0.24\mu s$ (max) (IC = 0.3A)

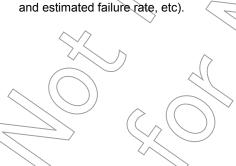
Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	600	(λ)	
Collector-emitter voltage		V _{CEX}	600	(\checkmark)	
Collector-emitter voltage		V _{CEO}	285	\bigvee	
Emitter-base voltage		V _{EBO}	8	→	
Collector current	DC	IC	1.0	A	
	Pulse	ICP	2.0		
Base current		ΙΒ	0.5	A	
Collector power dissipation	Ta = 25°C	Pc	1.0	⟨w	
Junction temperature		T _j ((150	°C	
Storage temperature range		Tstg	-55 to 150	√ °C	

Weight: g (typ.)

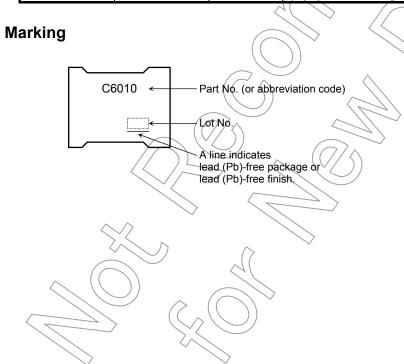
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report

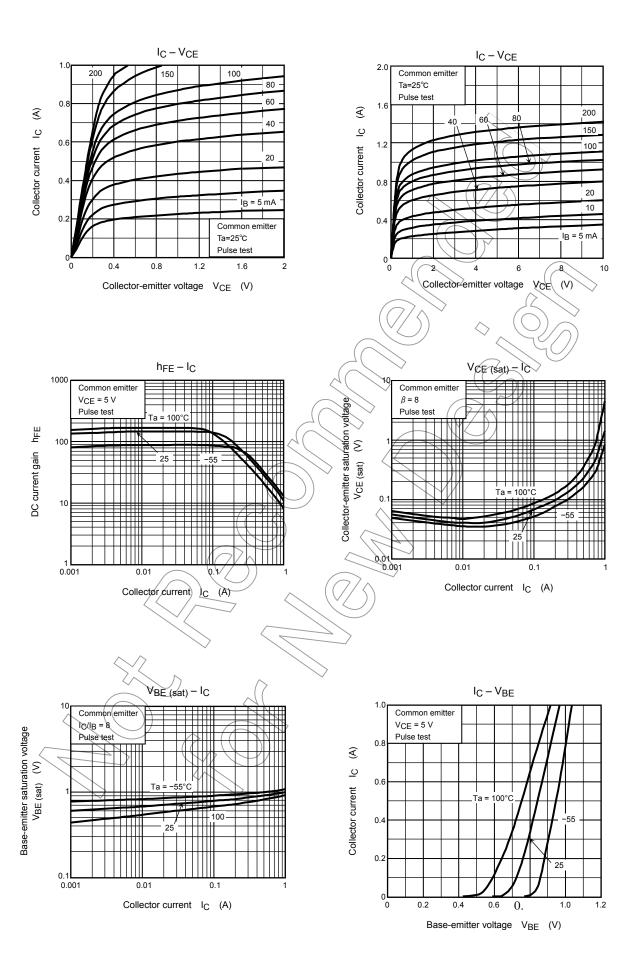


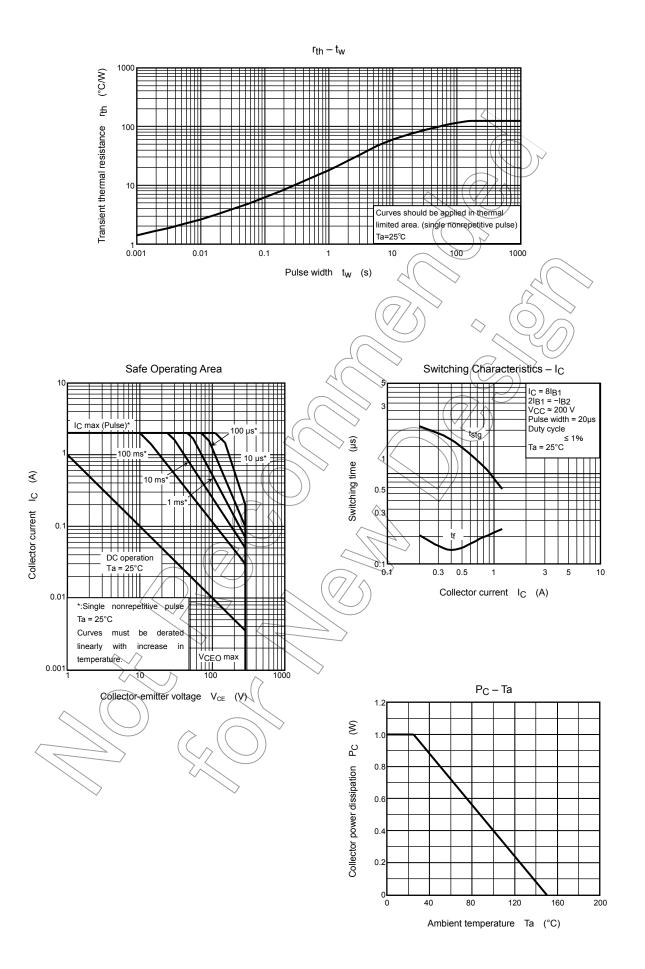
Electrical Characteristics (Ta = 25°C)

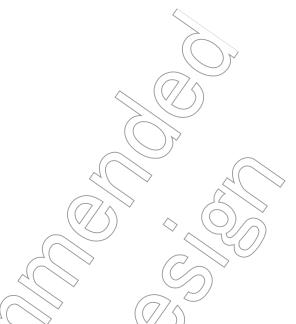
Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	urrent	I _{CBO}	V _{CB} = 600 V, I _E = 0	_	_	100	μΑ
Emitter cut-off cur	rrent	I _{EBO}	V _{EB} = 8 V, I _C = 0	_	_	100	μΑ
Collector-base br	eakdown voltage	V (BR) CBO	I _C = 1 mA, I _B = 0	600	_	-	٧
Collector-emitter	breakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	285	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA) >-	200	
		h _{FE} (2)	V _{CE} = 5 V, I _C = 0.1 A	100	_	200	
		h _{FE} (3)	V _{CE} = 5 V, I _C = 0.2 A	69	_	_	
Collector emitter saturation voltage		V _{CE} (sat)	I _C = 0.6 A, I _B = 75 mA	_	_	1.0	V
Base-emitter saturation voltage		V _{BE} (sat)	I _C = 0.6 A, I _B = 75 mA	^ —	_	1.3	V
Switching time	Rise time	t _r	20 µs	_		0.4	
	Storage time	t _{stg}	IB2 OUT-PUT			3.0	μs
	Fall time	t _f	I _{B1} = 20 mA, -I _{B2} ≠ 50 mA DUTY CYCLE ≤ 1%	2)	_	0.24	



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20070701-EN

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